

# Offline SMPS

Updated: JUN-2024

Industry	Industrial Automation – Power Conversion
Application	Offline SMPS is a classic product to convert grid power into DC power according to the end loads. As there are usually two power conversion stages, higher efficiency is always a goal. Higher efficiency can be achieved by using power switches with better performance or by implementing different control strategies. In addition, choose the most appropriate topology in different conditions. In this system solution guide, basics about offline SMPS will be delivered, together with the featured products and solutions provided by onsemi.

## System Purpose

Offline SMPS is widely used in every corner of human life which has been discussed and studied since last century. Offline SMPS generally refers to a switching power supply with an isolation transformer which is powered by the grid. It ranges from 65W in your laptop battery charger to thousands of watt in server power supply units in datacenters.

With the mass producing of wide-band gap semiconductor products, new topologies are utilized to reach optimized efficiency, size and integrated level according to real cases. New designed controllers can also contribute to the system safety, power consumption and performance.

“Zero carbon” has set more strict efficiency standards of energy saving and emission reduction on SMPS globally. For example, the European Union Executive Committee's latest CoC V5 and the U.S. Department of Energy DoE VI have clear requirements on the power loss and efficiency during not only full load, but light load/no load to achieve energy saving and emission reduction.

## System Implementations

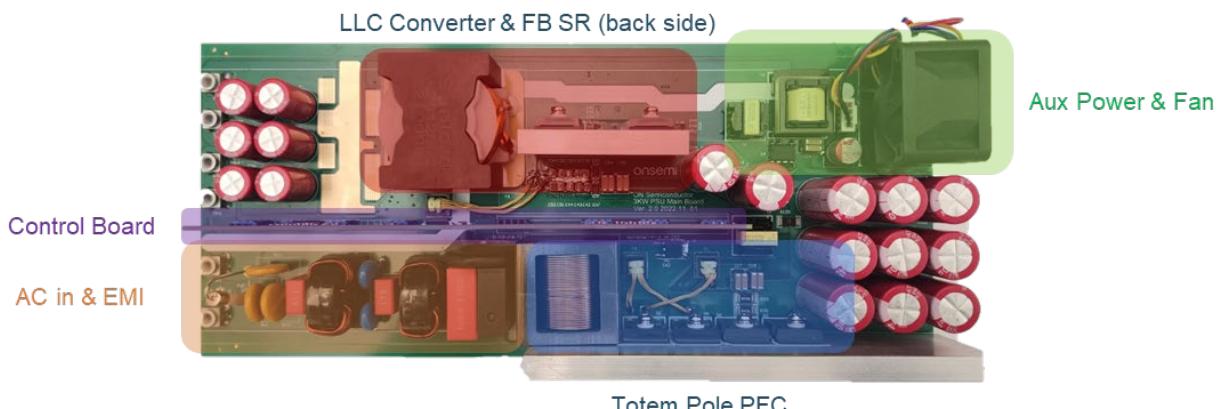


Fig 1: 3kw Totem Pole PFC + LLC PSU Reference Design

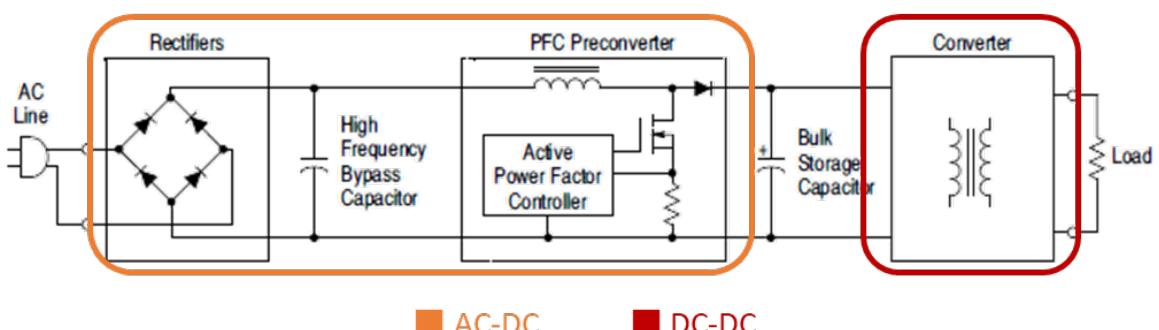


Fig 2: A Typical Offline SMPS

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## System Description

### Standards

There are mainly 3 types of standards. Safety standards like the 2nd edition of IEC 62368-1 is the latest revision clarifying the definitions of insulation, isolation, clearances, creepage distance, etc. IEC 61000-3-2 is an international emissions standard that limits mains voltage distortion by prescribing the maximum value for harmonic currents from the second harmonic up to and including the 40th harmonic current. It applies to equipment with a rated current up to 16A while for equipment above 16A, IEC 61000-3-12 should be followed.

There is a wide variety of regulations covering energy efficiency around the world, from the California Energy Commission to Energy Star and Energy-related Products (ErP). Specific to external power supplies (wall mount or desktop), the US Department of Energy (DoE) publishes a standard described in levels (Level VI is the most recent and most stringent), while in Europe, the European Union (EU) Code of Conduct (CoC) on External Power Supplies (EPS) is prepared by the Joint Research Centre, the European Commission's science, and knowledge service. The 80 PLUS® program promotes 80% efficiency or greater, between 20% and 100% loading and a power factor of 0.9 or higher at 100% loading. The highest level in this program (known as the 80+ Titanium standard) specifies a minimum efficiency of 92% at 20% loading and 94 % efficiency at 100 % loading.

### Power Factor Correction

PFC (Power Factor Correction) is a crucial stage for offline power supply. The key mission of PFC is to shape the input current to maximize the real power available from the mains, reduce the high-frequency harmonic current to minimizes losses and costs associated not only with the distribution of the power, but also with the generation of the power and the capital equipment involved in the process. THD (Total Harmonic Distortion) is an important method in determining the quality of line current in any system and is often mentioned in place of the power factor. Another important value is that PFC stage can provide regulated DC output voltage, optimizing the design of the following isolated DC-DC converter with a narrow DC input.

### DC-DC Stage

The purpose of a DC-DC stage is to convert a range of input voltages through an isolated transformer and PWM or resonant converter to a desired DC output voltage(s) and current(s). The key challenge of this stage is the magnetic component design. For example, the skin effect and proximity effect lead to eddy currents of a high-frequency transformer, selection of magnetic core materials, losses from core and copper, etc.

### Current Control Mode

It's necessary to repeat the classical operating modes as they can completely affect not only the choice of topology, but the entire system design. CCM (Continuous Conduction Mode) is more popular at higher power levels as it has minimal peak and rms currents. In CCM, the inductor current ripple is reduced, but the MOSFET turns on while the boost diode is conducting. Low  $t_{rr}$  diodes are now necessary to avoid excessive losses and stress at MOSFET turn on. CrM (Critical Conduction Mode) is very popular for low power applications. In this mode the inductor current reaches zero before the start of the next cycle and the frequency varies with line and load conditions. One benefit of CrM is that the current loop is intrinsically stable and there is no need for ramp compensation. In addition, the inductor current reaching zero every cycle causes the diode to turn off without reverse recovery losses and enables the use of a less expensive boost diode without performance penalties. Similarly, the MOSFET turn-on can be at a low voltage, which reduces switching losses.

DCM (Discontinuous Conduction Mode) is usually active at light loads of a CrM/CCM system to ensure power factor and limit the EMI generation because of the significant rising frequency near the zero crossing.

FCCrM (Frequency-Clamped Critical conduction Mode) is an approach introduced by **onsemi** to limit the switching frequency spread of CrM circuits. A maximum frequency clamp forces DCM when the converter operates in light-load and/or near the line zero crossing. Without this circuitry, the CrM switching frequency would exceed the upper clamp threshold, naturally increasing switching losses. A circuitry is added to compensate the DCM-engendered dead-times so that the line current keeps being properly shaped.

# Offline SMPS

## System Description

Table 1: Operation modes of switched mode power supplies

Waveform	Symbol	Features
	<u>Continuous Conduction Mode (CCM)</u>	<ul style="list-style-type: none"> <li>Always hard switching</li> <li>Large inductance</li> <li>Minimized rms current</li> </ul>
	<u>Critical Conduction Mode (CrM)</u>	<ul style="list-style-type: none"> <li>Highest rms current</li> <li>Unfixed switching frequency</li> </ul>
	<u>Discontinuous Conduction Mode (DCM)</u>	<ul style="list-style-type: none"> <li>Higher rms current</li> <li>Reduced inductance</li> <li>Best stability</li> </ul>

## Market Information & Trend

### Wide Band-gap Semiconductors

With the mass production of WBG devices, we are experiencing or will soon see SiC/GaN based SMPS. Utilizing the characteristics of these materials (better reverse recovery, excellent thermal performance, high operating voltage, high temperature), the new systems can operate at higher frequency, smaller PCB sizes and even without heatsink or forced cooling. However, high frequency will also bring potential issues like emissions, overshoot, etc., which means a completely new design.

### Integration

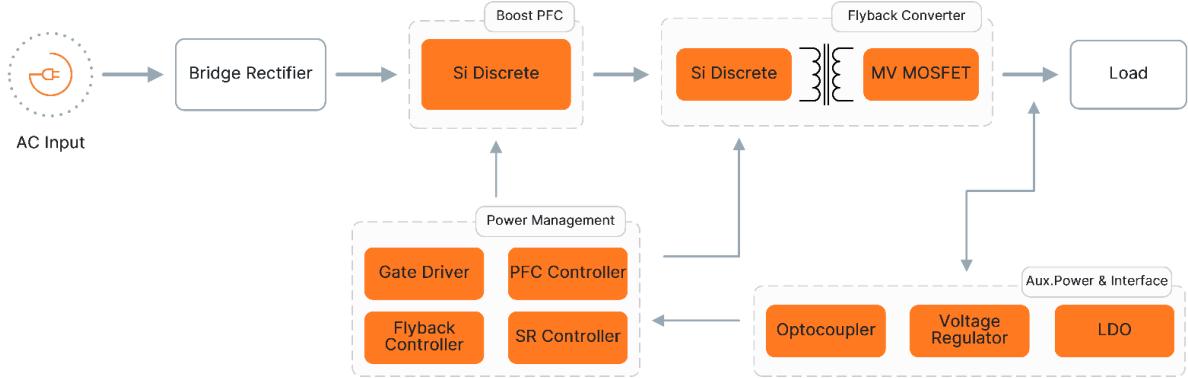
Integration is an effective way to save PCB space and external passive components, which finally increase the power density and flexibility of mounting. For example, GaN HEMT is a popular choice in low/med power supplies ( $P_{out} < 1500W$ ) for the minimized size of end-product. Under such circumstance that  $dv/dt$  might be over  $100V/ns$ , reduction of parasitic inductance is necessary. Integrating the GaN HEMT and driver in a same package can reduce the inductance caused by lead and PCB, result in a better switching performance.

### New Topologies for Better Efficiency

Totem pole PFC saves the losses caused by rectifier bridges, makes it a preferred PFC topology than single boost in high power density products. Now LLC is becoming the no.1 popular DC-DC topology in medium and high-power range for its wider range of soft switching, narrow frequency range with entire load change and smaller circulating current. WBG semiconductor plays a key role in these new topologies while a smart and low-power controller is another important factor for high efficiency.

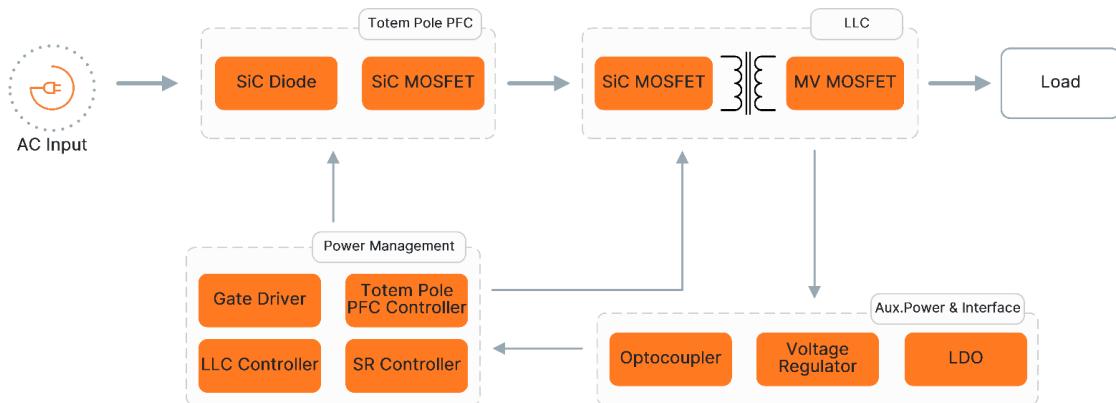
### Solution Overview

#### Offline Power Supply (Bridge PFC + Flyback Converter)

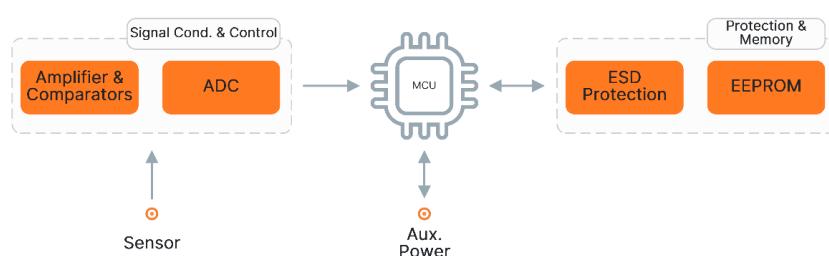


[Find Interactive Block Diagram on the Web](#)

#### Offline Power Supply (Totem Pole PFC + LLC Resonant Converter)



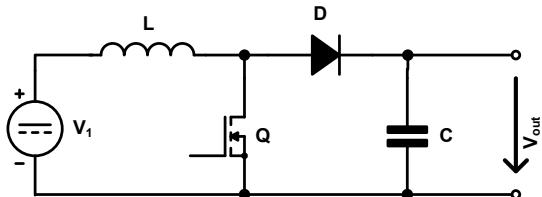
\*Optional



[Find Interactive Block Diagram on the Web](#)

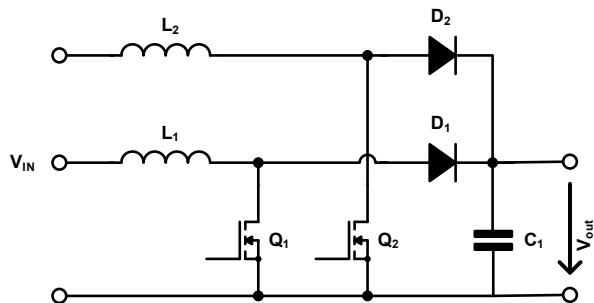
### Solution Overview

#### PFC



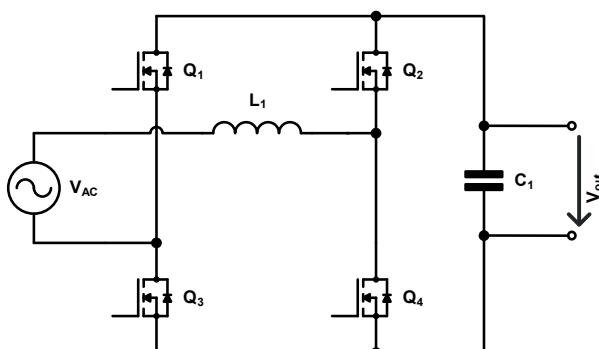
#### Single Boost PFC

- Simplest circuit and easiest control
- Low BOM cost, low failure rate
- Unavoidable losses caused by rectifiers
- Moderate size and EMI performance



#### Interleaved Boost PFC

- 2x/more power and passive components
- Switches are controlled with 180/120 degrees out of phase
- Unavoidable losses caused by rectifiers
- Improved efficiency and ripple current
- Improved total inductor size vs. a big single inductor
- An easy approach to improve output power



#### Totem Pole PFC

- Reduced power switch quantity
- More complex control than boost PFC
- Best efficiency and higher power with bridgeless structure
- WBG required in fast leg
- Emission and surge current issues
- Preferred in high-end PSU with power density/efficiency requirement

### Solution Overview



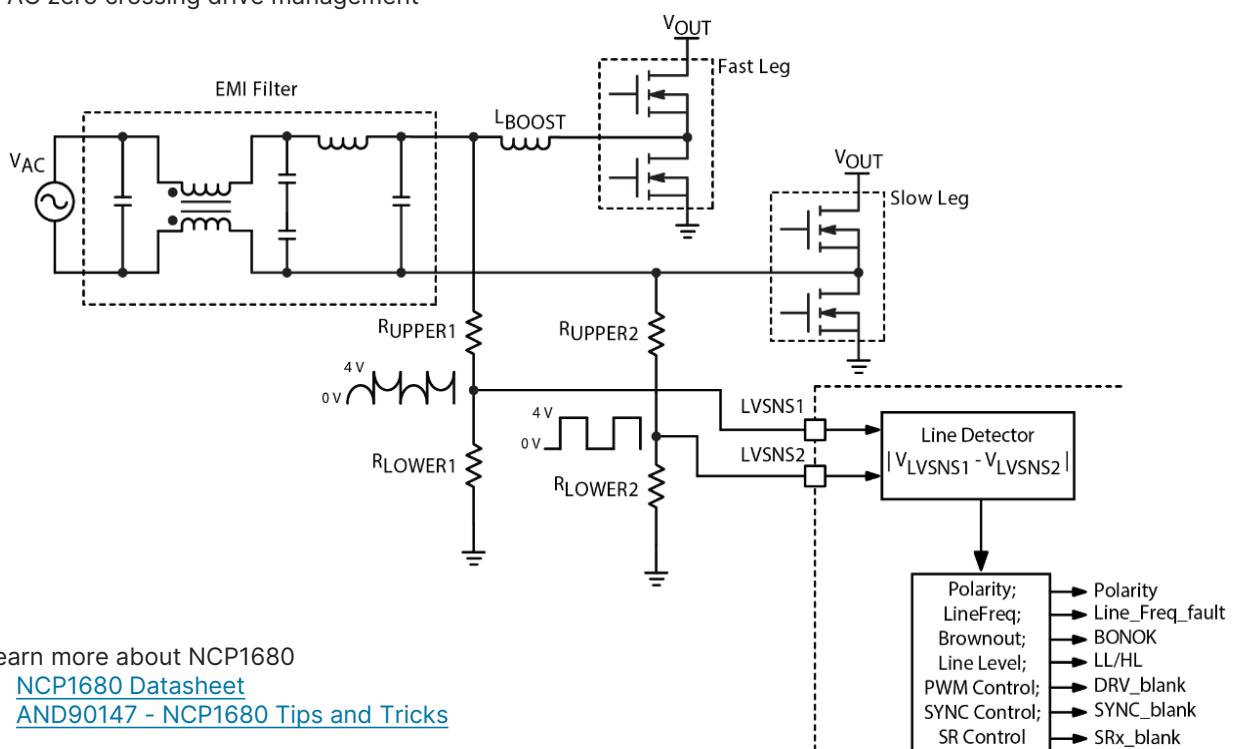
#### NCP1680 CrM Totem Pole PFC Controller

- Constant on-time CrM and valley switching frequency foldback
- AC line monitoring & phase detection
- Novel current sensing scheme
- UVLO, thermal shutdown
- Cycle by cycle current limit without hall sensor
- Target application – High power-density PSU

### Line Voltage Sensing of NCP1680

In the Totem Pole topology, the AC line voltage floats with respect to the controller ground. This necessitates a differential measurement technique to determine the AC line voltage magnitude. The NCP1680 employs differential voltage detection and rectification to reconstruct a waveform equal to  $|V_{LVSNS1} - V_{LVSNS2}|$ . The line voltage sensing will additionally be responsible for determining the polarity (i.e. positive or negative half-line cycle) of the AC voltage and the other important functions:

- a. AC Line Frequency Monitoring
- b. Brownout protection feature
- c. Line level detection
- d. AC zero crossing drive management



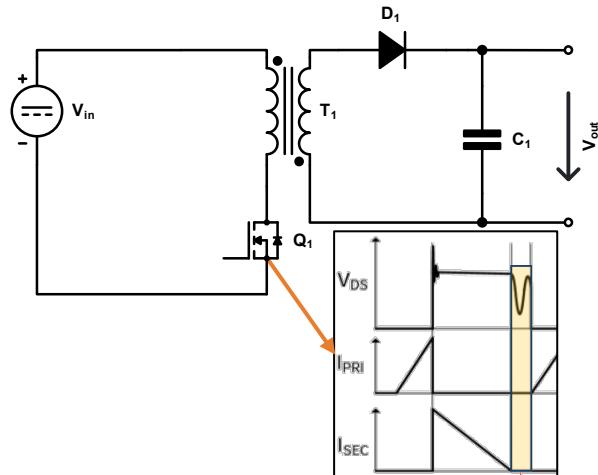
Learn more about NCP1680

- [NCP1680 Datasheet](#)
- [AND90147 - NCP1680 Tips and Tricks](#)

Fig 3: Line Sensing Configuration

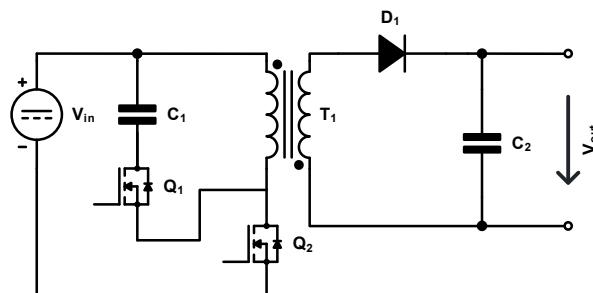
### Solution Overview

#### DC-DC Stage



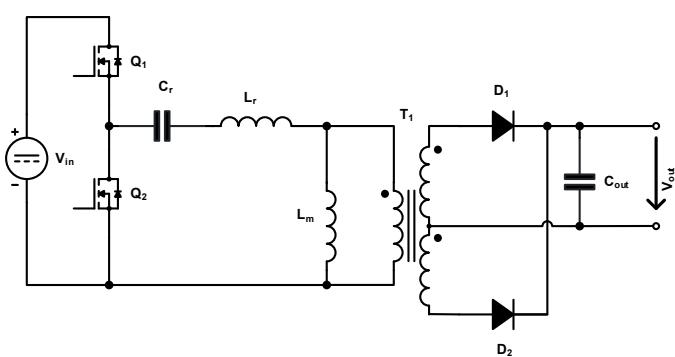
#### Quasi-Resonant (QR) Flyback

- Same circuit design as a classic flyback, low cost and simple design
- Valley switching to reduce losses after  $I_{sec}=0$
- Dangerous primary voltage spike caused by leakage inductance (converter to heat with RCD snubber)
- Targeting low output level (<200W)
- Need demagnetization detection



#### Active Clamp Flyback (ACF)

- Additional clamp switch is used to improve efficiency and protect main switch
- Recycle leakage inductance current instead of consuming it with a snubber
- Clamp capacitor and leakage inductance realize ZVS
- Medium output level is targeted (120W-240W)
- Need accurate resonant circuit parameter calculation



#### LLC

- Resonant converter achieve wide range of soft switching to improve efficiency
- ZVS at primary side, ZCS at secondary side
- Integrated inductor to save space
- Simple BOM, complicated resonant tank design and control algorithm
- Good EMI and output ripple
- Limited output range
- High output level is targeted (>240W)

### Solution Overview

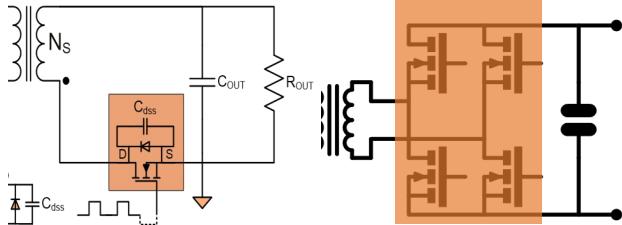
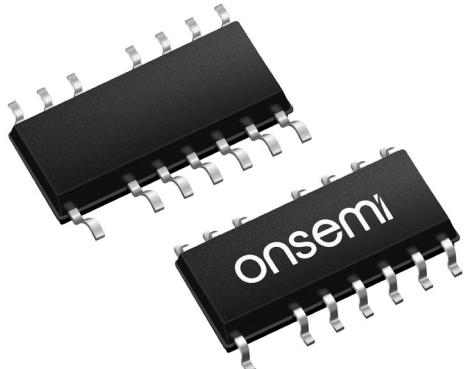


Fig 4: Synchronous rectification



### Dual Edge Tracking of NCP4390

NCP4390 uses a dual-edge-tracking method that anticipates the SR current zero-crossing instant with respect to two different time references. This technique not only minimizes the dead time during the normal operation but also provides stable SR control during any transient and mode change.

Learn more about NCP4390

- [NCP4390 Datasheet](#)
- [AND90061 - Half-Bridge LLC Resonant Converter Design Using NCP4390/NCV4390](#)

### Synchronous Rectification for Flyback/LLC

- Replacing diodes with MOSFET switches to reduce conduction losses and improve efficiency
- Accurate switching timing detection

### NCP4390

#### Dual Channel LLC Controller

- Constant on-time CrM and valley switching frequency foldback
- AC line monitoring & phase detection
- Novel current sensing scheme
- UVLO, thermal shutdown
- Cycle by cycle current limit without hall sensor
- Target application – High power-density PSU

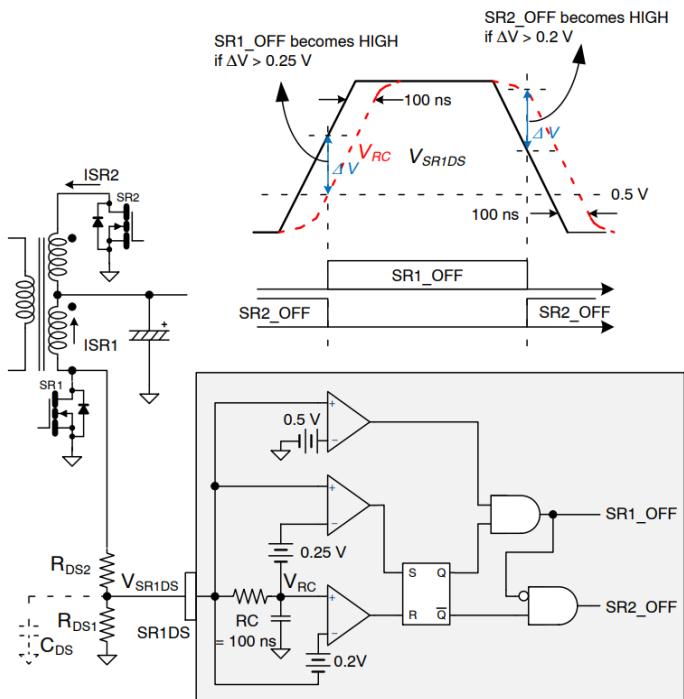


Fig 5: SR Conduction Detection with Single Pin

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## Recommended Products

Suggested Block	Part Number	Description
<b>Offline Power Supply (Bridge PFC + Flyback Converter)</b>		
<b>Boost PFC &amp; Flyback Converter (Primary Stage)</b>	<a href="#">NTD280N60S5Z</a>	Power MOSFET, N-Channel, 600V, 280mΩ, 13A, DPAK
	<a href="#">NTP125N60S5H</a>	Power MOSFET, N-Channel, 600V, 125mΩ, 22A, TO-220
	<a href="#">NTMT280N60S5Z</a>	Power MOSFET, N-Channel, 600V, 280mΩ, 13A, Power88
	<a href="#">NTBL150N60S5H</a>	Power MOSFET, N-Channel, 600V, 150mΩ, 19A, TOLL
	<a href="#">NTBL125N60S5H</a>	Power MOSFET, N-Channel, 600V, 125mΩ, 22A, TOLL
	Application Recommended Si MOSFET	
<b>Flyback Converter (Inc. Sync. Rectifier)</b>	<a href="#">MUR810G</a>	Power Rectifier, 100V, 8A, to-220
	<a href="#">MBR60H100CTG</a>	Schottky Rectifier, 100V, 60A, TO-220
	<a href="#">NRTS30100MFS</a>	Trench Schottky Rectifier, 100V, 30A, SO8-FL
	<a href="#">MBR41H100CTG</a>	Schottky Barrier Rectifier, 100V, 40A, TO-220
	Application Recommended Secondary Stage Diode	
	<a href="#">MURA160T3G</a>	Power Rectifier, 600V, 1A, SMA-2
	<a href="#">NRVUHS160V</a>	Ultrafast Rectifier, 600V, 1A, SMB-2
	<a href="#">MURHS160T3</a>	Ultrafast Rectifier, 600V, 1A, SMB2
	Application Recommended Snubber Diode	
	<a href="#">NTMFS0D4N04XM</a>	Power MOSFET, N-Channel, 40V, 0.7mΩ, 323A, SO8-FL 5x6
	<a href="#">NTMFWS1D5N08X</a>	Power MOSFET, N-Channel, STD Gate. SO8FL-HEFET, 80V, 1.5mΩ, 247 A
	<a href="#">NTBGS004N10G</a>	Power MOSFET, N-Channel, 203 A, 100V, D2PAK 7L
	<a href="#">NTMFS3D2N10MD</a>	N-Channel Shielded Gate PowerTrench® MOSFET 100V, 142A, 3.2mΩ
	<a href="#">NTMFS7D5N15MC</a>	N-Channel Shielded Gate PowerTrench® MOSFET 150V, 95.6A, 7.9mΩ
	Application Recommended SR MOSFET	
<b>Power Management</b>	<a href="#">NCP4305</a>	Sync. Rectification Driver for QR, Forward & LLC
	<a href="#">NCP4306</a>	Sync. Rectification Driver for QR, Forward & LLC
	<a href="#">NCP4307</a>	SR Driver with Dual Vcc and Self-supply for ACF, QR, Forward & LLC
	<a href="#">NCP4318</a>	Dual Channel Sync. Rectification Driver for LLC
	Application Recommended SR Controller	
	<a href="#">NCP1623</a>	Critical Conduction Mode (CrM) PFC Controller, Follower Boost
	<a href="#">NCP1632</a>	Critical Conduction Mode (CrM) PFC Controller, 2 Channel Interleaved
	<a href="#">NCP1618</a>	Multimode (CrM-CCM) PFC Controller, Active X2
	<a href="#">NCP1654</a>	Continuous Conduction Mode (CCM) PFC Controller
	<a href="#">NCP1616</a>	Critical Conduction Mode (CrM) PFC Controller, CCFF, Active X2
	Application Recommended PFC Controller	

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## Recommended Products

Suggested Block	Part Number	Description
Power Management	<a href="#">NCP1251</a>	PWM Controller, Current Mode for Offline Power Suppliers
	<a href="#">NCP1342</a>	Quasi-Resonant Flyback Controller with Valley Lock-out Switching
	<a href="#">NCP1343</a>	Quasi-Resonant Flyback Controller with Power Excursion Mode
	<a href="#">NCP1345</a>	Quasi-Resonant flyback controller for offline USB-PD and USB Type-C
	<a href="#">NCP1568</a>	AC-DC Active Clamp Flyback PWM Controller
	Application Recommended Flyback Controller	
	<a href="#">NCP51530</a>	High Performance, 700 V- 3.5/3.0 A High and Low Side MOSFET Driver
	<a href="#">NCP5183</a>	High Voltage 4.3 A High and Low Side Driver
	<a href="#">NCP51810</a>	High Performance, 150 V Half Bridge Gate Driver for GaN Power Switches
	<a href="#">NCP51561</a>	4.5/9A Isolated Dual Channel Gate Driver with 8V UVLO and DISABLE
Application Recommended Gate Driver		
Aux. Power & Interface	<a href="#">FOD817 series</a>	4-Pin DIP Phototransistor Optocouplers
	<a href="#">FOD217 series</a>	4-Pin Phototransistor Optocoupler In Half-Pitch Mini-Flat
	<a href="#">FODM100 series</a>	Single Channel, Phototransistor Optocoupler In Stretched Body SOP 4-Pin
	Application Recommended Optocoupler	
	<a href="#">NCP718</a>	LDO Regulator, 300 mA, Wide Vin, Ultra-Low Iq
	<a href="#">NCP730</a>	LDO Regulator, 150 mA, 38 V, 1 uA IQ, with PG
	<a href="#">NCP731</a>	LDO Regulator, 150 mA, 38 V, 8 µVrms with Enable and external Soft Start.
	<a href="#">NCP164</a>	LDO Regulator, 150 mA, Ultra-Low Noise, High PSRR with Power Good
	Application Recommended LDO	
	<a href="#">NCV6324</a>	Synchronous Buck Converter, 3 MHz, 2.0 A
Totem Pole PFC	<a href="#">LM257 series</a>	Buck Regulator, Switching Adjustable Output Voltage
	Application Recommended Voltage Regulator	
<b>Offline Power Supply (Totem Pole PFC + LLC Resonant Converter)</b>		
<a href="#">NTH4L023N065M3S</a>	SiC MOSFET - EliteSiC, 23 mΩ, 650 V, M3S, TO-247-4L	
<a href="#">NTHL023N065M3S</a>	SiC MOSFET - EliteSiC, 23 mΩ, 650 V, M3S, TO-247-3L	
<a href="#">NTBG023N065M3S</a>	SiC MOSFET - EliteSiC, 23 mΩ, 650 V, M3S, D2PAK-7L	
<a href="#">NTBG015N065SC1</a>	SiC MOSFET - EliteSiC, 12 mohm, 650 V, M2, D2PAK-7L	
<a href="#">NTBL045N065SC1</a>	SiC MOSFET - EliteSiC, 33 mohm, 650 V, M2, TOLL	
<a href="#">NTH4L015N065SC1</a>	SiC MOSFET - EliteSiC, 12 mohm, 650 V, M2, TO-247-4L	
<a href="#">NTMT045N065SC1</a>	SiC MOSFET - EliteSiC, 33 mohm, 650 V, M2, Power88	
<a href="#">NTHL075N065SC1</a>	SiC MOSFET - EliteSiC, 57 mohm, 650 V, M2, TO-247-3L	
Application Recommended SiC MOSFET		

### Recommended Products

Suggested Block	Part Number	Description
Totem Pole PFC	<a href="#">FFSD0665B</a>	SiC Schottky Diode – EliteSiC, 6 A, 650 V, D2, DPAK
	<a href="#">FFSP0665B</a>	SiC Schottky Diode – EliteSiC, 6 A, 650 V, D2, TO-220-2L
	<a href="#">FFSM0865B</a>	SiC Schottky Diode – EliteSiC, 8 A, 650 V, D2, Power88
	<a href="#">FFSB1065B</a>	SiC Schottky Diode – EliteSiC, 10 A, 650 V, D2, D2PAK-2L
	Application Recommended SiC Diode	
LLC	<a href="#">NTBG015N065SC1</a>	SiC MOSFET - EliteSiC, 12 mohm, 650 V, M2, D2PAK-7L
	<a href="#">NTBL045N065SC1</a>	SiC MOSFET - EliteSiC, 33 mohm, 650 V, M2, TOLL
	<a href="#">NTH4L015N065SC1</a>	SiC MOSFET - EliteSiC, 12 mohm, 650 V, M2, TO-247-4L
	<a href="#">NTMT045N065SC1</a>	SiC MOSFET - EliteSiC, 33 mohm, 650 V, M2, Power88
	<a href="#">NTHL075N065SC1</a>	SiC MOSFET - EliteSiC, 57 mohm, 650 V, M2, TO-247-3L
	Application Recommended SiC MOSFET	
	<a href="#">NTMFS0D4N04XM</a>	Power MOSFET, N-Channel, 40V, 0.7mΩ, 323A, SO8-FL 5x6
	<a href="#">NTMFWS1D5N08X</a>	Power MOSFET, N-Channel, STD Gate. SO8FL-HEFET, 80V, 1.5mΩ, 247 A
	<a href="#">NTBGS004N10G</a>	Power MOSFET, N-Channel, 203 A, 100V, D2PAK 7L
	<a href="#">NTMFS3D2N10MD</a>	N-Channel Shielded Gate PowerTrench® MOSFET 100V, 142A, 3.2mΩ
	<a href="#">NTMFS7D5N15MC</a>	N-Channel Shielded Gate PowerTrench® MOSFET 150V, 95.6A, 7.9mΩ
	Application Recommended MV MOSFET	
Power Management Gate Driver	<a href="#">NCP51530</a>	High Performance, 700 V- 3.5/3.0 A High and Low Side MOSFET Driver
	<a href="#">NCP5183</a>	High Voltage 4.3 A High and Low Side Driver
	<a href="#">NCP51810</a>	High Performance, 150 V Half Bridge Gate Driver for GaN Power Switches
	<a href="#">NCP51561</a>	4.5/9A Isolated Dual Channel Gate Driver with 8V UVLO and DISABLE
	Application Recommended Gate Driver	
	<a href="#">NCP1680</a>	Totem Pole CrM Power Factor Correction Controller
	<a href="#">NCP1681</a>	Totem Pole CCM/ Multi-mode (CrM-CCM) PFC Controller
	Application Recommended Totem Pole PFC Controller	
	<a href="#">NCP4390</a>	Resonant Controller with Sync. Rectifier Control, Enhanced Light Load
	<a href="#">NCP13992</a>	Current Mode Resonant Controller with Integrated High Voltage Drivers, Enhanced Light Load
	<a href="#">NCP13994</a>	Current Mode Resonant Controller with Integrated High Voltage Drivers, Enhanced Protections, Active X2
	Application Recommended LLC Converter Controller	

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Power Management Gate Driver	<a href="#">NCP4305</a>	Sync. Rectification Driver for QR, Forward & LLC
	<a href="#">NCP4306</a>	Sync. Rectification Driver for QR, Forward & LLC
	<a href="#">NCP4307</a>	SR Driver with Dual Vcc and Self-supply for ACF, QR, Forward & LLC
	<a href="#">NCP4318</a>	Dual Channel Sync. Rectification Driver for LLC
	<a href="#">Application Recommended SR Controller</a>	
Aux. Power & Interface	<a href="#">FOD817 series</a>	4-Pin DIP Phototransistor Optocouplers
	<a href="#">FOD217 series</a>	4-Pin Phototransistor Optocoupler In Half-Pitch Mini-Flat
	<a href="#">FODM100 series</a>	Single Channel, Phototransistor Optocoupler In Stretched Body SOP 4-Pin
	<a href="#">Application Recommended Optocoupler</a>	
	<a href="#">NCP718</a>	LDO Regulator, 300 mA, Wide Vin, Ultra-Low Iq
	<a href="#">NCP730</a>	LDO Regulator, 150 mA, 38 V, 1 uA IQ, with PG
	<a href="#">NCP731</a>	LDO Regulator, 150 mA, 38 V, 8 µVRms with Enable and external Soft Start.
	<a href="#">NCP164</a>	LDO Regulator, 150 mA, Ultra-Low Noise, High PSRR with Power Good
	<a href="#">Application Recommended LDO</a>	
	<a href="#">NCV6324</a>	Synchronous Buck Converter, 3 MHz, 2.0 A
	<a href="#">LM257 series</a>	Buck Regulator, Switching Adjustable Output Voltage
	<a href="#">Application Recommended Voltage Regulator</a>	
<b>Optional Parts - Offline Power Supply (Totem Pole PFC + LLC Resonant Converter)</b>		
Signal Cond. & Control	<a href="#">NCS21 series</a>	Current Sense Amplifier, 26V, Low-/High-Side Voltage Out
	<a href="#">NCS2007 series</a>	Operational Amplifier, Wide Supply Range, 3MHz CMOS
	<a href="#">LM393</a>	Comparator, Dual, Low Offset Voltage
	<a href="#">Application Recommended Amplifier &amp; Comparator</a>	
Protection & Memory	<a href="#">CAT24M01</a>	EEPROM Serial 1 MB I2C
	<a href="#">CAT24C64</a>	EEPROM Serial 64 kb I2C
	<a href="#">Application Recommended EEPROM</a>	
	<a href="#">NCID9 series</a>	High Speed Dual/3ch/Quad Digital Isolator
	<a href="#">NIS3071</a>	Electronic fuse (eFuse) 4-channel, 8V to 60V, 10A in 5x6mm package
	<a href="#">MM5Z series</a>	500 mW Tight Tolerance Zener Diode Voltage Regulator

# Offline SMPS

Updated: JUN-2024

## Development Tools & Resources

### Product Recommendation Tools+

Product Recommendations or Database of Products by **onsemi**

[Find Products](#)

### WebDesigner+

Utilize WebDesigner+ to design a power supply tailored to your specific requirements.

[Generate & Optimize](#)

### Simulation SPICE models

Simulation SPICE Models Files for **onsemi** Products

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### Interactive Block Diagrams

Block Diagrams of **onsemi** Solutions and Their BOM Worksheets

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### Evaluation and Development Tools

Evaluation or Development Boards Database by **onsemi**

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### Elite Power Simulator

Perform simulations for our EliteSiC MOSFETs, modules, FieldStop7 IGBTs and PowerTrench® T10 MOSFETs using appropriate engineering tools and software.

[Simulate Now](#)

### Self-Service PLECS Model Generator

Increase Accuracy with Customization and Improve Circuit Performance

[Generate PLECS Model](#)

# Offline SMPS

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## Technical Documents

Type	Description & Link
<b>Power Discrete</b>	
Whitepaper	<a href="#">Silicon Carbide (SiC) – From Challenging Material to Robust Reliability</a>
Whitepaper	<a href="#">Physically Based, Scalable SPICE Modeling Methodologies for Modern Power Electronic Devices</a>
Application Note	<a href="#">Mounting Considerations for Power Semiconductors</a>
<b>Gate Driver</b>	
Application Note	<a href="#">NCD(V)57000/57001 Gate Driver Design Note</a>
Whitepaper	<a href="#">SiC MOSFETs: Gate Drive Optimization</a>
Application Note	<a href="#">Practical Design Guidelines on the Usage of an Isolated Gate Driver</a>
Application Note	<a href="#">Design and Application Guide of Bootstrap Circuit for High-Voltage Gate-Drive IC</a>
Application Note	<a href="#">Analysis of Power Dissipation and Thermal Considerations for High Voltage Gate Drivers</a>
<b>Power Factor Correction</b>	
Whitepaper	<a href="#">Meeting Challenging Efficiency Standards with Bridgeless Totem Pole Power Factor Correction</a>
Application Note	<a href="#">Power Factor Correction Basics</a>
Whitepaper	<a href="#">Power Factor Correction – Optimization Options</a>
Application Note	<a href="#">Design Guideline for 3-Ch Interleaved CCM PFC Using the FAN9673 5kW CCM PFC Controller</a>
Whitepaper	<a href="#">Totem Pole PFC Layout Considerations</a>
Application Note	<a href="#">Key Steps to Design A Compact, High-Efficiency PFC Stage Using NCP1623A</a>
Application Note	<a href="#">CrM Totem Pole PFC IC Tips and Tricks</a>
Application Note	<a href="#">Key Steps to Design a Multimode PFC Stage Using the NCP1618A</a>
Application Note	<a href="#">FAN9672/3 Tips and Tricks</a>
<b>Flyback</b>	
Whitepaper	<a href="#">High-Density AC-DC Power Supplies using Active-Clamp Flyback Topology</a>
Application Note	<a href="#">Design of a 100W ACF DC-DC Converter for Telecom System Using NCP1262</a>
<b>LLC</b>	
Application Note	<a href="#">Half-Bridge LLC Resonant Converter Design Using NCP4390/NCV4390</a>
Application Note	<a href="#">Understanding the LLC Structure in Resonant Applications</a>

### Technical Documents

Type	Description & Link
<b>Miscellaneous</b>	
Application Note	<a href="#">Current Sense Amplifiers, FAQ</a>
<b>Application Overview</b>	
Collateral	<a href="#">Power Supply Solutions</a>
Whitepaper	<a href="#">Popular Topologies in Offline Power Supplies</a>
White Paper	<a href="#">Meeting Ultra-High-Density Design Challenges with GaN-based 300W Totem Pole PFC and LLC Power Supply</a>
Evaluation Board	<a href="#">High Performance 800 V Off-line Switcher with HV Startup and SenseFET Evaluation Board</a>
Evaluation Board	<a href="#">NCP1345 USB-PD 65W Evaluation Board</a>
Evaluation Board	<a href="#">NCP1343 100 W USB PD Evaluation Board</a>
White Paper	<a href="#">3kW Totem-Pole PFC and Secondary-Side Regulated LLC Power Supply Using SiC MOSFETs</a>
Design Tool	<a href="#">NCP1680 Design Calculator</a>
Design Tool	<a href="#">NCP1681 Totem Pole Multi-Mode Controller Design Excel Calculator</a>
Design Tool	<a href="#">NCP1681 Totem Pole CCM Controller Design Excel Calculator</a>
Design Tool	<a href="#">NCP1681 Design Worksheet</a>
Design Tool	<a href="#">NCP134x Design Tool</a>
Design Tool	<a href="#">NCP1399x Design Tool</a>





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